

## DMOS Stepper Motor Driver with Translator

#### **Features and Benefits**

- Low R<sub>DS(on)</sub> outputs
- Automatic current decay mode detection/selection
- Mixed and Slow current decay modes
- Synchronous rectification for low power dissipation
- Internal UVLO and thermal shutdown circuitry
- Crossover-current protection

# Package: 24 pin SOICW with internally fused leads (suffix LB)



Not to scale

#### **Description**

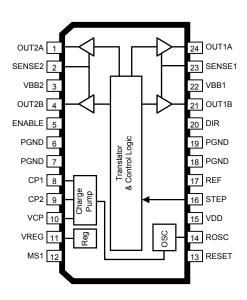
The A3982 is a complete stepper motor driver with built-in translator for easy operation. It is designed to operate bipolar stepper motors in full- and half-step modes, with an output drive capacity of up to 35 V and  $\pm 2$  A. The A3982 includes a fixed off-time current regulator which has the ability to operate in Slow or Mixed decay modes.

The translator is the key to the easy implementation of the A3982. Simply inputting one pulse on the STEP input drives the motor one step. There are no phase sequence tables, high frequency control lines, or complex interfaces to program. The A3982 interface is an ideal fit for applications where a complex microprocessor is unavailable or is overburdened.

The chopping control in the A3982 automatically selects the current decay mode (Slow or Mixed). When a signal occurs at the STEP input pin, the A3982 determines if that step results in a higher or lower current in each of the motor phases. If the change is to a higher current, then the decay mode is set to Slow decay. If the change is to a lower current, then the current decay is set to Mixed (set initially to a fast decay for a period amounting to 31.25% of the

Continued on the next page...

#### Pin-out Diagram



### A3982

## DMOS Stepper Motor Driver with Translator

#### **Description (continued)**

fixed off-time, then to a slow decay for the remainder of the off-time). This current decay control scheme results in reduced audible motor noise, increased step accuracy, and reduced power dissipation.

Internal synchronous rectification control circuitry is provided to improve power dissipation during PWM operation.

Internal circuit protection includes: thermal shutdown with hysteresis, undervoltage lockout (UVLO), and crossover-current protection. Special power-on sequencing is not required.

The A3982 is supplied in a 24-pin wide-body SOIC (package LB) with internally-fused power ground leads for enhanced thermal dissipation. It is lead (Pb) free, with 100% matte tin plated leadframe.

#### **Selection Guide**

| Part Number  | Packing*             | Package                                    |
|--------------|----------------------|--|
| A3982SLB-T   | 31 pieces per tube   | 24-pin Wide SOIC with pins 6 and 7, and 18 |
| A3982SLBTR-T | 1000 pieces per reel | and 19, fused internally                   |

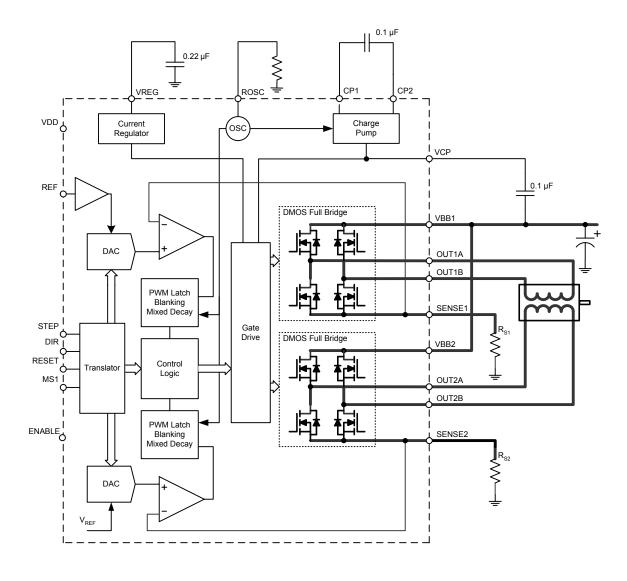
<sup>\*</sup>Contact Allegro for additional packing options

#### **Absolute Maximum Ratings**

| Characteristic                | Symbol               | Notes  | Rating     |    |
|-------------------------------|----------------------|--|------------|----|
| Load Supply Voltage           | V <sub>BB</sub>      |  | 35         | V  |
| Logic Input Voltage           | V <sub>IN</sub>      |  | -0.3 to 7  | V  |
| Sense Voltage                 | V <sub>SENSE</sub>   |  | 0.5        | V  |
| Reference Voltage             | V <sub>REF</sub>     |  | 4          | V  |
| Output Current                | І <sub>оит</sub>     | Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of conditions, do not exceed the specified current rating or a junction temperature of 150°C. | ±2         | А  |
| Operating Ambient Temperature | T <sub>A</sub>       | Range S  | -20 to 85  | °C |
| Maximum Junction Temperature  | T <sub>J</sub> (max) |  | 150        | °C |
| Storage Temperature           | T <sub>stg</sub>     |  | -55 to 150 | °C |



### Functional Block Diagram





### **ELECTRICAL CHARACTERISTICS**<sup>1</sup> at $T_A = 25$ °C, $V_{BB} = 35$ V (unless otherwise noted)

| Characteristics                       | Symbol               | Test Conditions  | Min.                 | Typ. <sup>2</sup> | Max.                | Units |
|---------------------------------------|----------------------|--|----------------------|-------------------|---------------------|-------|
| Output Drivers                        |                      |  |                      |                   | •                   |       |
| Load Supply Voltage Range             | V <sub>BB</sub>      | Operating  | 8                    | _                 | 35                  | V     |
| Logic Supply Voltage Range            | $V_{DD}$             | Operating  | 3.0                  | _                 | 5.5                 | V     |
| Output On Basistanas                  |                      | Source Driver, I <sub>OUT</sub> = -1.5 A               | _                    | 0.370             | 0.460               | Ω     |
| Output On Resistance                  | R <sub>DSON</sub>    | Sink Driver, I <sub>OUT</sub> = 1.5 A                  | -                    | 0.330             | 0.380               | Ω     |
| Body Diode Forward Voltage            | \/                   | Source Diode, I <sub>F</sub> = -1.5 A                  | -                    | _                 | 1.2                 | V     |
| Body Diode Forward Voltage            | V <sub>F</sub>       | Sink Diode, I <sub>F</sub> = 1.5 A                     | _                    | _                 | 1.2                 | V     |
| Motor Supply Current                  |                      | f <sub>PWM</sub> < 50 kHz                              | _                    | -                 | 4                   | mA    |
| Wotor Supply Current                  | l <sub>BB</sub>      | Operating, outputs disabled                            | _                    | -                 | 2                   | mA    |
| Logic Supply Current                  |                      | f <sub>PWM</sub> < 50 kHz                              | _                    | -                 | 8                   | mA    |
| Logic Supply Current                  | I <sub>DD</sub>      | Outputs off  | _                    | _                 | 5                   | mA    |
| Control Logic                         |                      |  | •                    |                   | •                   |       |
| Logic Input Voltage                   | V <sub>IN(1)</sub>   |  | V <sub>DD</sub> ×0.7 | -                 | _                   | V     |
| Logic Input Voltage                   | V <sub>IN(0)</sub>   |  | _                    | _                 | $V_{DD} \times 0.3$ | V     |
| Logic Input Current                   | I <sub>IN(1)</sub>   | $V_{IN} = V_{DD} \times 0.7$                           | -20                  | <1.0              | 20                  | μA    |
| Logic input ourient                   | I <sub>IN(0)</sub>   | $V_{IN} = V_{DD} \times 0.3$                           | -20                  | <1.0              | 20                  | μA    |
| Input Hysteresis                      | V <sub>HYS(IN)</sub> |  | 150                  | 300               | 500                 | mV    |
| Blank Time                            | t <sub>BLANK</sub>   |  | 0.7                  | 1                 | 1.3                 | μs    |
| Fixed Off-Time                        |                      | OSC > 3 V  | 20                   | 30                | 40                  | μs    |
| Fixed Oil-Tillie                      | t <sub>OFF</sub>     | $R_{OSC} = 25 k\Omega$                                 | 23                   | 30                | 37                  | μs    |
| Reference Input Voltage Range         | $V_{REF}$            |  | 0                    | _                 | 4                   | V     |
| Reference Input Current               | I <sub>REF</sub>     |  | -3                   | 0                 | 3                   | μA    |
| Current Trip-Level Error <sup>3</sup> |                      | V <sub>REF</sub> = 2 V, %I <sub>TripMAX</sub> = 70.71% | _                    | _                 | ±5                  | %     |
| Current Imp-Level Entire              | err <sub>l</sub>     | $V_{REF} = 2 \text{ V}, \%I_{TripMAX} = 100.00\%$      | _                    | -                 | ±5                  | %     |
| Crossover Dead Time                   | t <sub>DT</sub>      |  | 100                  | 475               | 800                 | ns    |
| Protection                            |                      |  |                      |                   |                     |       |
| Thermal Shutdown Temperature          | TJ                   |  | -                    | 165               | -                   | °C    |
| Thermal Shutdown Hysteresis           | T <sub>JHYS</sub>    |  | _                    | 15                | -                   | °C    |
| UVLO Enable Threshold                 | UV <sub>LO</sub>     | V <sub>DD</sub> rising                                 | 2.35                 | 2.7               | 3                   | V     |
| UVLO Hysteresis                       | UV <sub>HYS</sub>    |  | 0.05                 | 0.10              | _                   | V     |

<sup>&</sup>lt;sup>1</sup>Negative current is defined as coming out of (sourcing from) the specified device pin.



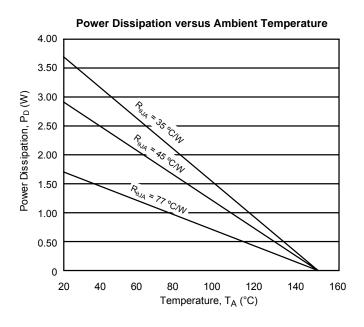
<sup>&</sup>lt;sup>2</sup>Typical data are for initial design estimations only, and assume optimum manufacturing and application conditions. Performance may vary for individual units, within the specified maximum and minimum limits.

 $<sup>^{3}</sup>$ err<sub>I</sub> =  $(I_{Trip} - I_{Prog})/I_{Prog}$ , where  $I_{Prog}$  =  $\%I_{TripMAX} \times I_{TripMAX}$ .

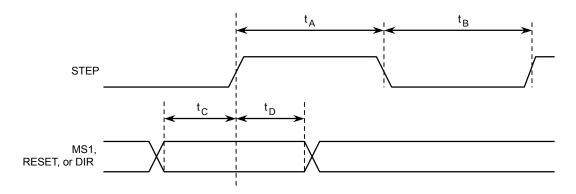
#### THERMAL CHARACTERISTICS

| Characteristic             | Symbol         | Test Conditions*  | Value | Units |
|----------------------------|----------------|---|-------|-------|
| Package Thermal Resistance | $R_{	heta JA}$ | One-layer PCB, one-sided with copper limited to solder pads   | 77    | °C/W  |
|                            |                | One-layer PCB, two-sided with copper limited to solder pads and 3.57 in. <sup>2</sup> of copper area on each side, connected to PGND pins | 45    | °C/W  |
|                            |                | Four-layer PCB, based on JEDEC standard   | 35    | °C/W  |

<sup>\*</sup>Additional thermal information available on Allegro Web site.







| Time Duration                    | Symbol         | Тур. | Unit |
|----------------------------------|----------------|------|------|
| STEP minimum, HIGH pulse width   | t <sub>A</sub> | 1    | μs   |
| STEP minimum, LOW pulse width    | t <sub>B</sub> | 1    | μs   |
| Setup time, input change to STEP | t <sub>C</sub> | 200  | ns   |
| Hold time, input change to STEP  | t <sub>D</sub> | 200  | ns   |

Figure 1. Logic Interface Timing Diagram

Table 1. Stepping Resolution Truth Table

| MS1 | Step Resolution | Excitation Mode |
|-----|-----------------|-----------------|
| L   | Full Step       | 2 Phase         |
| Н   | Half Step       | 1-2 Phase       |

### **Functional Description**

**Device Operation.** The A3982 is a complete stepper motor driver with a built-in translator for easy operation with minimal control lines. It is designed to operate bipolar stepper motors in full- and half-step modes. The currents in each of the two output full-bridges and all of the N-channel DMOS FETs are regulated with fixed off-time PMW (pulse width modulated) control circuitry. At each step, the current for each full-bridge is set by the value of its external current-sense resistor ( $R_{S1}$  or  $R_{S2}$ ), a reference voltage ( $V_{REF}$ ), and the output voltage of its DAC (which in turn is controlled by the output of the translator).

At power-on or reset, the translator sets the DACs and the phase current polarity to the initial Home state (shown in figures 2 and 3), and the current regulator to Mixed Decay Mode for both phases. When a step command signal occurs on the STEP input, the translator automatically sequences the DACs to the next level and current polarity. (See table 2 for the current-level sequence.) The step resolution is set by input MS1, as shown in table 1.

When stepping, if the new output levels of the DACs are lower than their previous output levels, then the decay mode for the active full-bridge is set to Mixed. If the new output levels of the DACs are higher than or equal to their previous levels, then the decay mode for the active full-bridge is set to Slow. This automatic current decay selection improves stepping performance by reducing the distortion of the current waveform that results from the back EMF of the motor.

**RESET Input (RESET).** The RESET input sets the translator to a predefined Home state (shown in figures 2 and 3), and turns off all of the DMOS outputs. All STEP inputs are ignored until the RESET input is set to high.

**Step Input (STEP).** A low-to-high transition on the STEP input sequences the translator and advances the motor one increment. The translator controls the input to the DACs and the direction of current flow in each winding. The size of the

increment is determined by input MS1, as shown in table 1.

**Direction Input (DIR).** This determines the direction of rotation of the motor. When low, the direction will be clockwise and when high, counterclockwise. Changes to this input do not take effect until the next STEP rising edge.

**Internal PWM Current Control.** Each full-bridge is controlled by a fixed off-time PWM current control circuit that limits the load current to a desired value,  $I_{TRIP}$ . Initially, a diagonal pair of source and sink DMOS outputs are enabled and current flows through the motor winding and the current sense resistor,  $R_{Sx}$ . When the voltage across  $R_{Sx}$  equals the DAC output voltage, the current sense comparator resets the PWM latch. The latch then turns off either the source DMOS FET (when in Slow Decay Mode) or the sink and source DMOS FETs (when in Mixed Decay Mode).

The maximum value of current limiting is set by the selection of  $R_{Sx}$  and the voltage at the VREF pin. The transconductance function is approximated by the maximum value of current limiting,  $I_{TripMAX}$  (A), which is set by

$$I_{TripMAX} = V_{REF} / (8 \times R_S)$$

where  $R_S$  is the resistance of the sense resistor ( $\Omega$ ) and  $V_{REF}$  is the input voltage on the REF pin (V).

The DAC output reduces the  $V_{REF}$  output to the current sense comparator in precise steps, such that

$$I_{trip} = (\%I_{TripMAX} / 100) \times I_{TripMAX}$$

(See table 2 for %I<sub>TripMAX</sub> at each step.)

It is critical that the maximum rating (0.5 V) on the SENSE1 and SENSE2 pins is not exceeded.

**Fixed Off-Time.** The internal PWM current control circuitry uses a one-shot circuit to control the duration of time that the DMOS FETs remain off. The one shot off-time,  $t_{OFE}$ ,



is determined by the selection of an external resistor connected from the ROSC timing pin to ground. If the ROSC pin is tied to an external voltage > 3 V, then  $t_{OFF}$  defaults to 30  $\mu$ s. The ROSC pin can be safely connected to the VDD pin for this purpose. The value of  $t_{OFF}$  ( $\mu$ s) is approximately

$$t_{OFF} \approx R_{OSC} / 825$$

**Blanking.** This function blanks the output of the current sense comparators when the outputs are switched by the internal current control circuitry. The comparator outputs are blanked to prevent false overcurrent detection due to reverse recovery currents of the clamp diodes, and switching transients related to the capacitance of the load. The blank time,  $t_{\rm BLANK}$  ( $\mu$ s), is approximately

$$t_{\rm BLANK} \approx 1 \ \mu s$$

Charge Pump (CP1 and CP2). The charge pump is used to generate a gate supply greater than that of VBB for driving the source-side DMOS gates. A 0.1  $\mu$ F ceramic capacitor, should be connected between CP1 and CP2. In addition, a 0.1  $\mu$ F ceramic capacitor is required between VCP and VBB, to act as a reservoir for operating the high-side DMOS gates.

**VREG (VREG).** This internally-generated voltage is used to operate the sink-side DMOS outputs. The VREG pin must be decoupled with a  $0.22~\mu F$  ceramic capacitor to ground. VREG is internally monitored. In the case of a fault condition, the DMOS outputs of the A3982 are disabled.

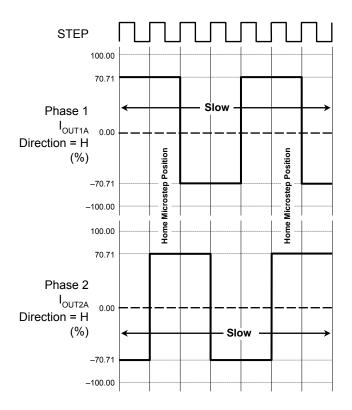
**Enable Input (ENABLE).** This input turns on or off all of the DMOS outputs. When set to a logic high, the outputs are disabled. When set to a logic low, the internal control enables the outputs as required. The translator inputs STEP, DIR, and MS1, as well as the internal sequencing logic, all remain active, independent of the ENABLE input state.

**Shutdown.** In the event of a fault, overtemperature (excess T<sub>J</sub>) or an undervoltage (on VCP), the DMOS outputs of the A3982 are disabled until the fault condition is removed. At power-on, the UVLO (undervoltage lockout) circuit disables the DMOS outputs and resets the translator to the Home state.

**Mixed Decay Operation.** The bridge can operate in Mixed Decay Mode, depending on the step sequence, as shown in figures 3 thru 5. As the trip point is reached, the A3982 initially goes into a fast decay mode for 31.25% of the off-time, t<sub>OFF</sub>. After that, it switches to Slow Decay Mode for the remainder of t<sub>OFF</sub>.

**Synchronous Rectification.** When a PWM-off cycle is triggered by an internal fixed—off-time cycle, load current recirculates according to the decay mode selected by the control logic. This synchronous rectification feature turns on the appropriate FETs during current decay, and effectively shorts out the body diodes with the low DMOS R<sub>DSON</sub>. This reduces power dissipation significantly, and can eliminate the need for external Schottky diodes in many applications. Turning off synchronous rectification prevents the reversal of the load current when a zero-current level is detected.





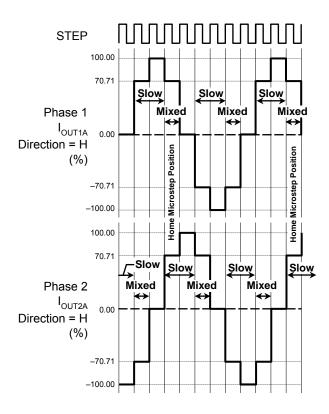


Figure 2. Decay Mode for Full-Step Increments

Figure 3. Decay Modes for Half-Step Increments

Table 2. Step Sequencing Settings Home step position at Step Angle 45°; DIR = H

| Full<br>Step | Half<br>Step<br># | Phase 1<br>Current<br>[% I <sub>tripMax</sub> ]<br>(%) | Phase 2<br>Current<br>[% I <sub>tripMax</sub> ]<br>(%) | Step<br>Angle<br>(º) |
|--------------|-------------------|--|--|----------------------|
|              | 1                 | 100.00   | 0.00   | 0.0                  |
| 1            | 2                 | 70.71  | 70.71  | 45.0                 |
|              | 3                 | 0.00   | 100.00   | 90.0                 |
| 2            | 4                 | -70.71   | 70.71  | 135.0                |
|              | 5                 | -100.00  | 0.00   | 180.0                |
| 3            | 6                 | -70.71   | -70.71   | 225.0                |
|              | 7                 | 0.00   | -100.00  | 270.0                |
| 4            | 8                 | 70.71  | -70.71   | 315.0                |



## A3982

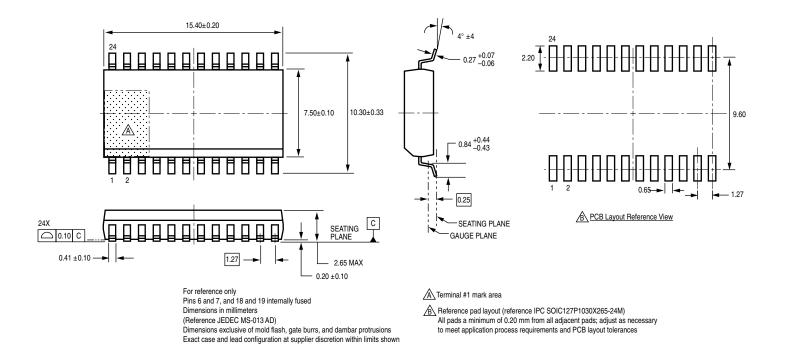
## DMOS Stepper Motor Driver with Translator

#### Pin List Table

| Name   | Description                          | Number |
|--------|--------------------------------------|--------|
| OUT2A  | DMOS Full Bridge 2 Output A          | 1      |
| SENSE2 | Sense resistor for Bridge 2          | 2      |
| VBB2   | Load supply                          | 3      |
| OUT2B  | DMOS Full Bridge 2 Output B          | 4      |
| ENABLE | Logic input                          | 5      |
| PGND   | Power ground                         | 6      |
| PGND   | Power ground                         | 7      |
| CP1    | Charge pump capacitor 1              | 8      |
| CP2    | Charge pump capacitor 2              | 9      |
| VCP    | Reservoir capacitor                  | 10     |
| VREG   | Regulator decoupling                 | 11     |
| MS1    | Logic input                          | 12     |
| RESET  | Logic input                          | 13     |
| ROSC   | Timing set                           | 14     |
| VDD    | Logic supply                         | 15     |
| STEP   | Logic input                          | 16     |
| REF    | Current trip reference voltage input | 17     |
| PGND   | Power ground                         | 18     |
| PGND   | Power ground                         | 19     |
| DIR    | Logic input                          | 20     |
| 1OUT1B | DMOS Full Bridge 1 Output B          | 21     |
| VBB1   | Load supply                          | 22     |
| SENSE1 | Sense resistor for Bridge 1          | 23     |
| OUT1A  | DMOS Full Bridge 1 Output A          | 24     |



#### LB Package, 24-Pin Wide Body SOIC



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